

# 2MBI400N-060

IGBT Module

600V / 400A 2 in one-package

## ■ Features

- High speed switching
- Voltage drive
- Low inductance module structure

## ■ Applications

- Inverter for Motor drive
- AC and DC Servo drive amplifier
- Uninterruptible power supply
- Industrial machines, such as Welding machines



## ■ Maximum ratings and characteristics

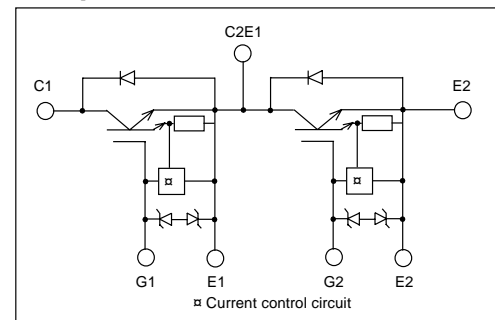
● Absolute maximum ratings (at  $T_c=25^\circ\text{C}$  unless otherwise specified)

| Item                      | Symbol       | Rating          | Unit             |
|---------------------------|--------------|-----------------|------------------|
| Collector-Emitter voltage | $V_{CES}$    | 600             | V                |
| Gate-Emitter voltage      | $V_{GES}$    | $\pm 20$        | V                |
| Collector current         | Continuous   | $I_c$           | 400 A            |
|                           | 1ms          | $I_c$ pulse     | 800 A            |
|                           | Continuous   | $-I_c$          | 400 A            |
|                           | 1ms          | $-I_c$ pulse    | 800 A            |
| Max. power dissipation    | $P_c$        | 1500            | W                |
| Operating temperature     | $T_j$        | +150            | $^\circ\text{C}$ |
| Storage temperature       | $T_{stg}$    | -40 to +125     | $^\circ\text{C}$ |
| Isolation voltage         | $V_{is}$     | AC 2500 (1min.) | V                |
| Screw torque              | Mounting *1  | 3.5             | N·m              |
|                           | Terminals *2 | 4.5             | N·m              |

\*1 : Recommendable value : 2.5 to 3.5 N·m(M5) or (M6)

\*2 : Recommendable value : 3.5 to 4.5 N·m(M6)

## ■ Equivalent Circuit Schematic



● Electrical characteristics (at  $T_j=25^\circ\text{C}$  unless otherwise specified)

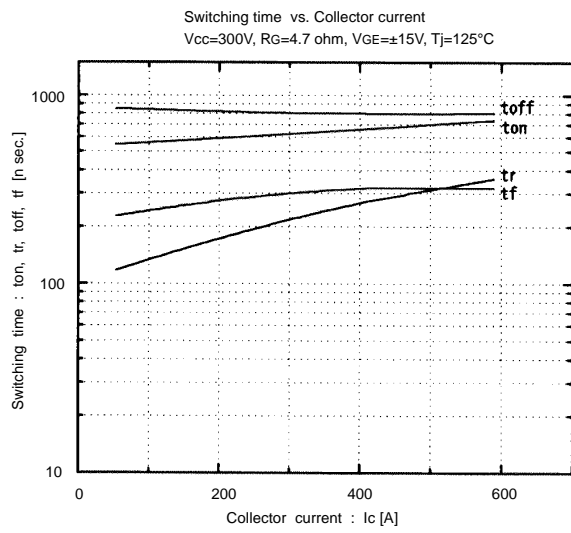
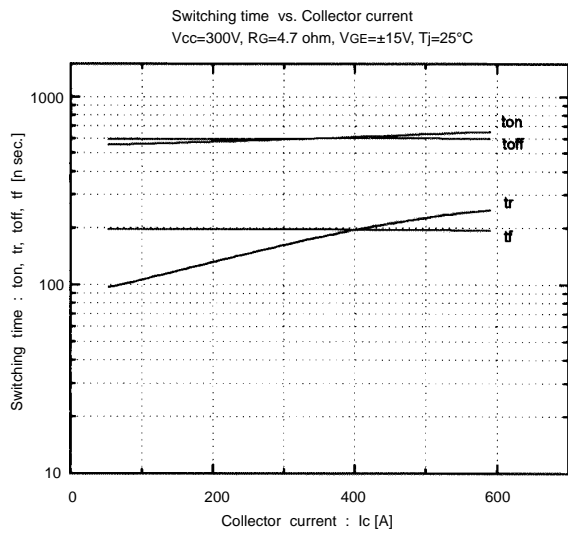
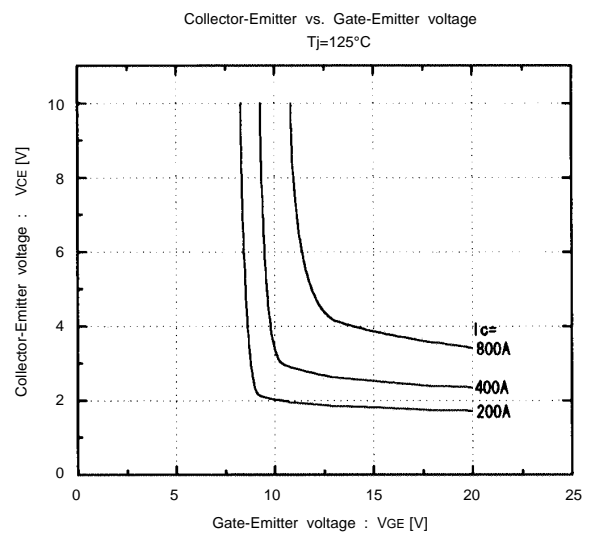
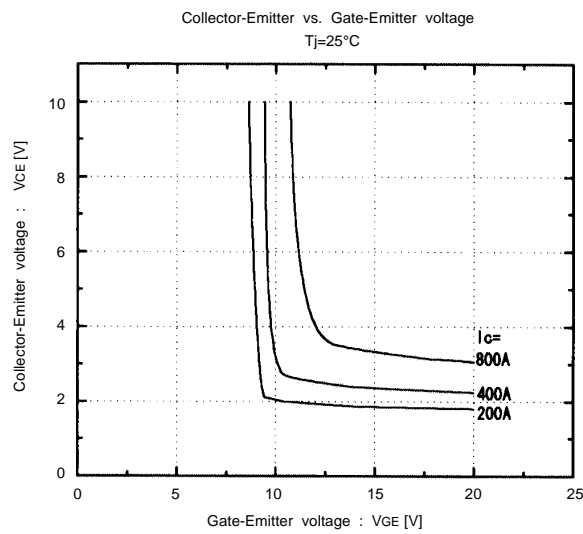
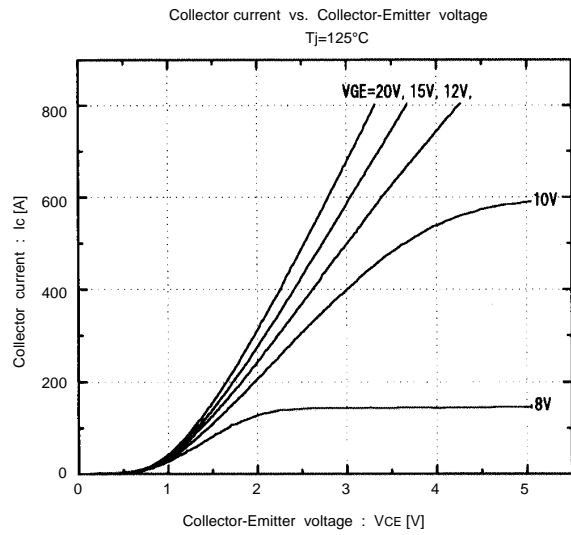
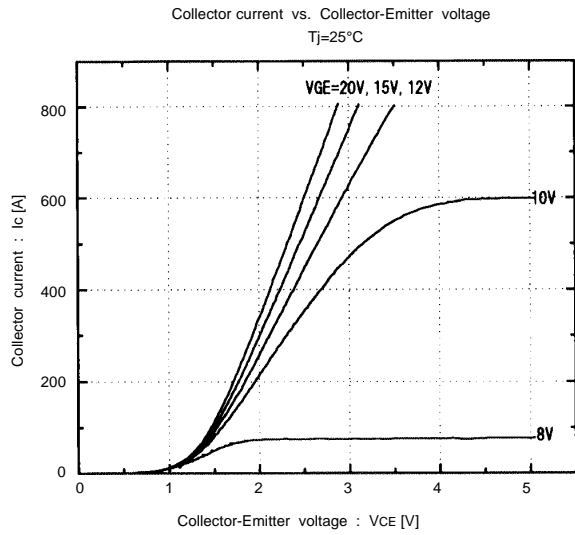
| Item                                 | Symbol        | Characteristics |       |      | Conditions                     | Unit          |
|--------------------------------------|---------------|-----------------|-------|------|--------------------------------|---------------|
|                                      |               | Min.            | Typ.  | Max. |                                |               |
| Zero gate voltage collector current  | $I_{CES}$     | -               | -     | 2.0  | $V_{GE}=0V, V_{CE}=600V$       | mA            |
| Gate-Emitter leakage current         | $I_{GES}$     | -               | -     | 30   | $V_{CE}=0V, V_{GE}=\pm 20V$    | $\mu\text{A}$ |
| Gate-Emitter threshold voltage       | $V_{GE(th)}$  | 4.5             | -     | 7.5  | $V_{CE}=20V, I_c=400\text{mA}$ | V             |
| Collector-Emitter saturation voltage | $V_{CE(sat)}$ | -               | -     | 2.8  | $V_{GE}=15V, I_c=400A$         | V             |
| Input capacitance                    | $C_{ies}$     | -               | 26400 | -    | $V_{GE}=0V$                    | $\text{pF}$   |
| Output capacitance                   | $C_{oes}$     | -               | 5870  | -    | $V_{CE}=10V$                   |               |
| Reverse transfer capacitance         | $C_{res}$     | -               | 2670  | -    | $f=1\text{MHz}$                |               |
| Turn-on time                         | $t_{on}$      | -               | 0.6   | 1.2  | $V_{CC}=300V$                  | $\mu\text{s}$ |
|                                      | $t_r$         | -               | 0.2   | 0.6  | $I_c=400A$                     |               |
| Turn-off time                        | $t_{off}$     | -               | 0.6   | 1.0  | $V_{GE}=\pm 15V$               |               |
|                                      | $t_f$         | -               | 0.2   | 0.35 | $R_G=4.7\ \text{ohm}$          |               |
| Diode forward on voltage             | $V_F$         | -               | -     | 3.0  | $I_F=400A, V_{GE}=0V$          | V             |
| Reverse recovery time                | $t_{rr}$      | -               | -     | 0.3  | $I_F=400A$                     | $\mu\text{s}$ |

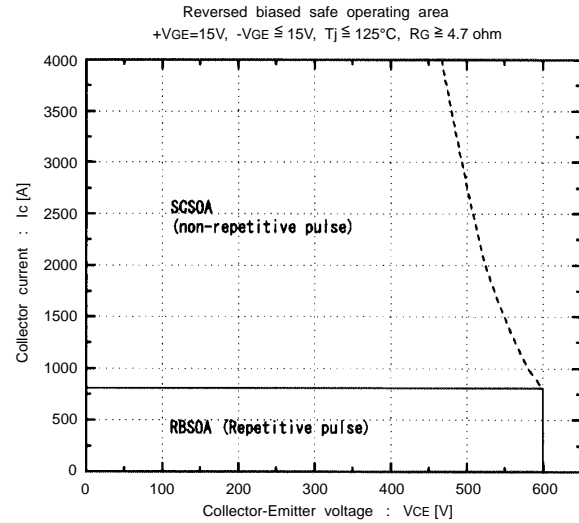
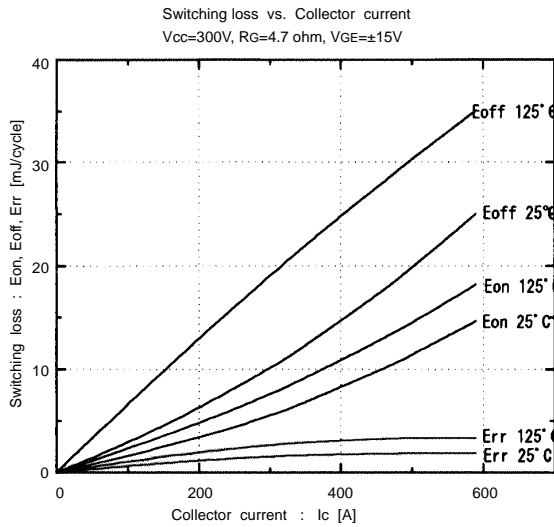
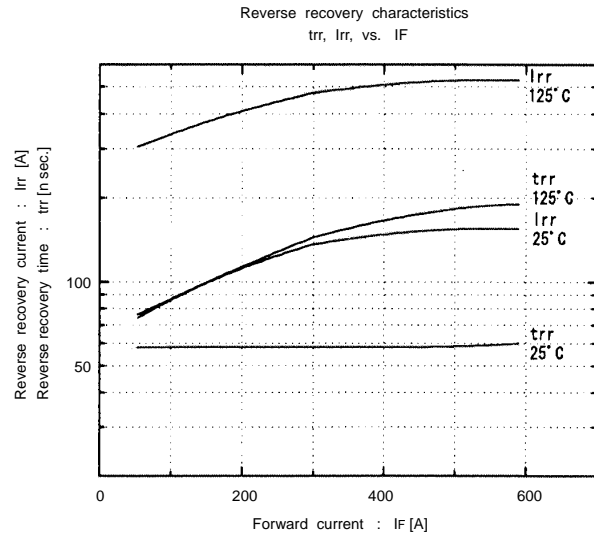
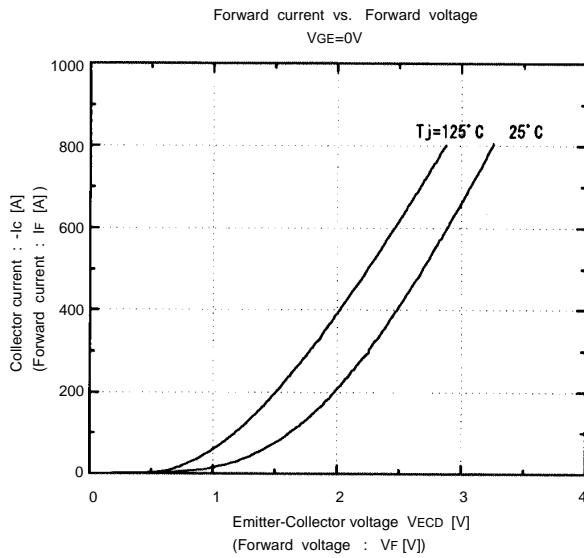
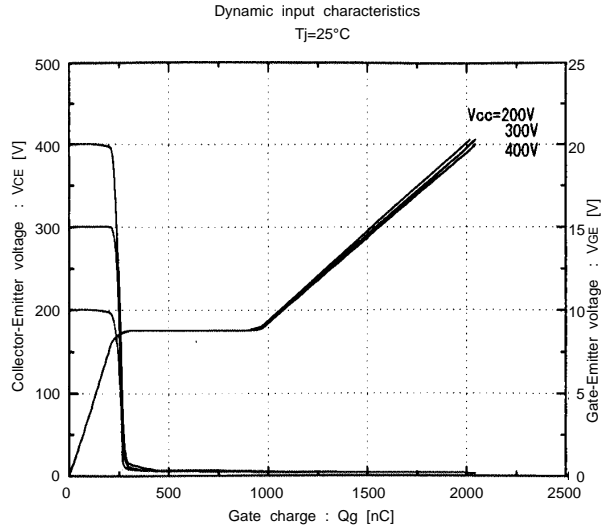
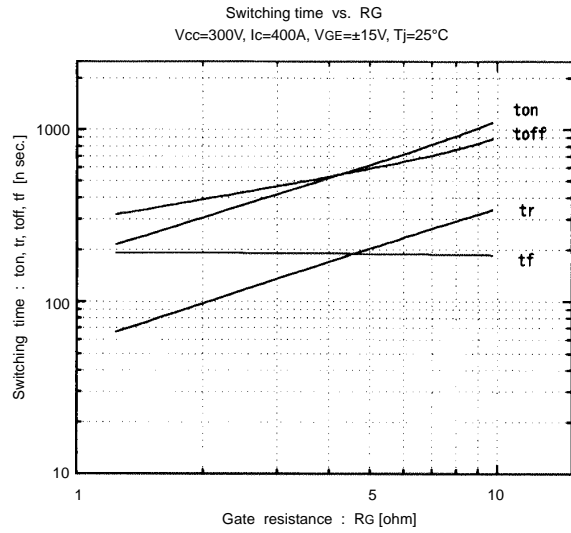
● Thermal resistance characteristics

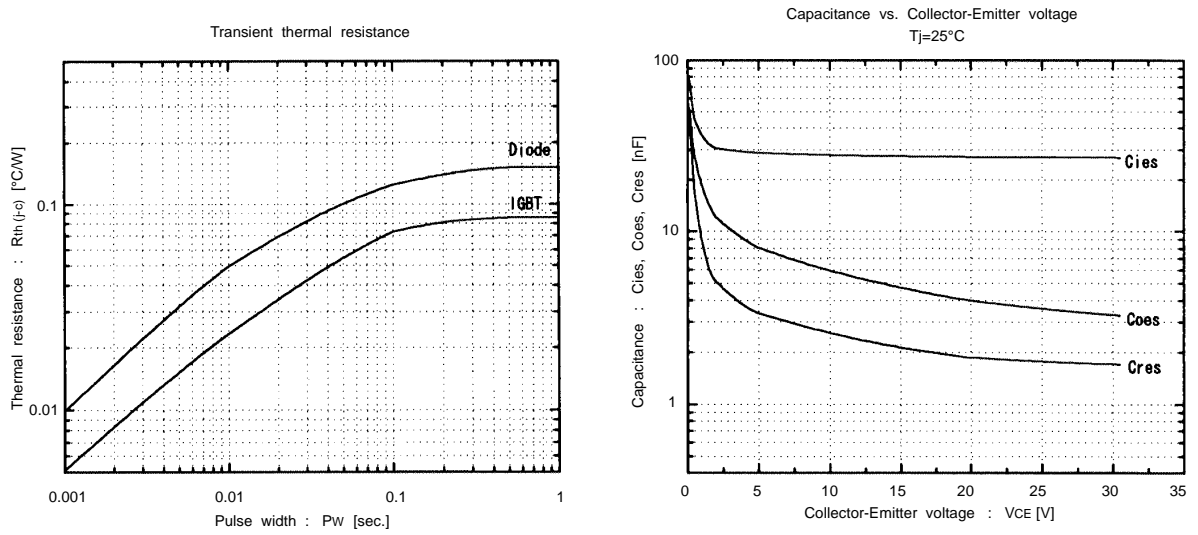
| Item               | Symbol           | Characteristics |       |       | Conditions              | Unit               |
|--------------------|------------------|-----------------|-------|-------|-------------------------|--------------------|
|                    |                  | Min.            | Typ.  | Max.  |                         |                    |
| Thermal resistance | $R_{th(j-c)}$    | -               | -     | 0.085 | IGBT                    | $^\circ\text{C/W}$ |
|                    | $R_{th(j-c)}$    | -               | -     | 0.15  | Diode                   | $^\circ\text{C/W}$ |
|                    | $R_{th(c-f)}^*3$ | -               | 0.025 | -     | the base to cooling fin | $^\circ\text{C/W}$ |

\*3 : This is the value which is defined mounting on the additional cooling fin with thermal compound

■ Characteristics (Representative)







■ Outline Drawings, mm

